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LASER WORKING DEVICE

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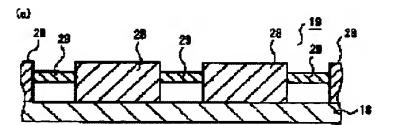
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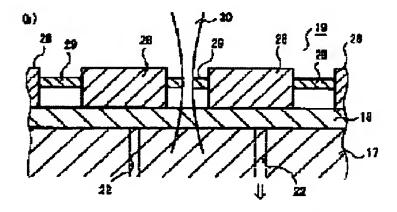
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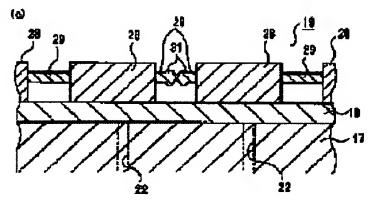
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Abstract of **JP2000164535**

PROBLEM TO BE SOLVED: To provide a laser working device, capable of easily mounting or dismounting a work without degrading the quality of the work. SOLUTION: A laser working device, for irradiating a semiconductor wafer 19 with a laser beam 30 and melting down the semiconductor wafer, has a fixing sheet member 18 made of a material which transmits the laser beam 30 and for bonding and fixing the semiconductor wafer 19 having a portion absorbing the laser light 30, and a mounting base 17 made of a material which transmits the laser beam 30 and for mounting and fixing the fixing sheet member 18.

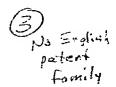






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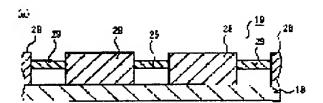
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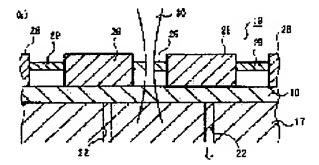
(54) LASER WORKING DEVICE

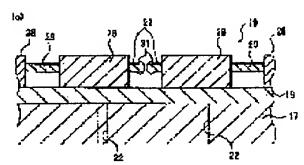
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PROBLEM TO BE SOLVED: To provide a laser working device, capable of easily mounting or dismounting a work without degrading the quality of the work.

SOLUTION: A laser working device, for irradiating a semiconductor wafer 19 with a laser beam 30 and melting down the semiconductor wafer, has a fixing sheet member 18 made of a material which transmits the laser beam 30 and for bonding and fixing the semiconductor wafer 19 having a portion absorbing the laser light 30, and a mounting base 17 made of a material which transmits the laser beam 30 and for mounting and fixing the fixing sheet member 18.







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DETAILED DESCRIPTION

[Detailed Description of the Invention]

[0001]

[Field of the Invention] A workpiece can be easily detached and attached from laser-beam-machining equipment, without starting laser-beam-machining equipment for this invention performing chip separation of the semiconductor device of a semi-conductor wafer as a workpiece, and reducing the quality of a workpiece.

[0002]

[Description of the Prior Art] Conventionally, as the chip separation approach of a semi-conductor wafer, there was a dance cut method by the diamond wheel. This approach is an approach one side sticks a wafer on the sheet-like ingredient which changes with adhesive tape, cuts a little sheet-like ingredient deeply, and cuts a wafer completely. However, by this approach, since there were many rates of the metallic material in the separation section, when the thickness of the separation section was set to 100 micrometers or less, there were metaled weld flash and a trouble that a crack occurred to a wafer.

[0003] As an approach for solving that, the method of performing chip separation of a semi-conductor wafer to JP,8-264491,A in a laser beam is proposed. <u>Drawing 5</u> R> 5 is drawing showing the chip separation approach of the semiconductor device in JP,8-264491,A. It is based on a Fig. below and the approach of chip separation of a semi-conductor wafer is explained.

[0004] First, when the semi-conductor wafer 3 as a workpiece connected, respectively in the metal section 2 of which between each semiconductor device 1 consists with nickel excellent in absorption of a laser beam is formed as shown in <u>drawing 5</u> (a) for example, this semi-conductor wafer 3 is pasted up on the adhesion side side of the firmly attached seat member 4 which has an adhesive property on one side, and it fixes (<u>drawing 5</u> (b)). Next, as shown in <u>drawing 6</u>, it is held after the stop ring 5 has pulled the perimeter of the firmly attached seat member 4, and the semi-conductor wafer 3 will be in the condition that it is held in the air.

[0005] And this stop ring 5 is being fixed to the body section 6 of laser-beam-machining equipment with the fixed jig 7. Next, a laser beam 8 is irradiated with a desired beam diameter at the metal section 2 of the semi-conductor wafer 3 (drawing 5 (c)). And a dissolution part melts with surface tension, the metal section 2 separates, is carried out [it fuses, and], the dissolution coagulation section 9 is formed, and each semiconductor device 1 is separated (drawing 5 (d)).

[0006] Then, the firmly attached seat member 4 is removed from laser-beam-machining equipment. Next, the firmly attached seat member 4 is pulled and lengthened, and between each separated semiconductor device 1 is extended. If it does in this way, each semiconductor device 1 can be easily removed from the firmly attached seat member 4.

[0007] If each semiconductor device 1 is separated as mentioned above, while irradiating the laser beam 8, the temperature of the semi-conductor wafer 3 rises and the location of elongation and the semi-conductor wafer 3 under processing moves [the firmly attached seat member 4] vertically and horizontally in connection with this. For this reason, focal gap of a laser beam 8 arose during processing, and there was a trouble that process tolerance fell.

[0008] In order to solve this, as shown in <u>drawing 8</u>, the installation base 11 equipped with many holes 10 for adsorption is formed on the body 6 of laser-beam-machining equipment, and the firmly attached seat member 4 to which the semi-conductor wafer 3 was fixed is laid on this installation base 11. Next, in order to stick the perimeter of the firmly attached seat member 4, and the top face of the installation base 11, it presses down with the fixed jig 12 from on the firmly attached seat member 4.

[0009] Next, opening wide the bulb 15 of the vacuum pump 13 which was open for free passage in the hole 10 for adsorption, and checking with the vacuum gage 14, desired negative pressure is applied from the hole 10 for adsorption with a vacuum pump 13, and the installation base 11 is made to carry out vacuum adsorption of the firmly attached seat member 4. Next, it is processed like the above-mentioned conventional case by the laser beam 8, maintaining this condition (drawing 7 (a)). And a dissolution part melts with surface tension, the metal section 2 separates, is carried out [it fuses, and], the dissolution coagulation section 9 is formed, and each semiconductor device 1 is separated (drawing 7 (b)). [0010] Then, while stopping a vacuum pump 13, a bulb 15 is closed and it opens wide to atmospheric pressure, and vacuum adsorption is canceled, and the firmly attached seat member 4 is removed from laser-beam-machining equipment. Next, the firmly attached seat member 4 is pulled and lengthened, between each separated semiconductor device 1 is extended, and each semiconductor device 1 is removed from the firmly attached seat member 4.

[0011] If such laser-beam-machining equipment is used, since the solid-state sheet member 4 is fixed on the installation base 11, it is canceled and gap of the firmly attached seat member 4 at the time of the exposure of a laser beam 8 can perform processing excellent in precision.

[0012] Without damaging a laser beam 8, the quality of the material of the installation base 11 used here is excellent in process tolerance, and, generally can consider use of acetal resin from points, such as low cost. However, as shown in <u>drawing 9</u>, when a laser beam 8 is irradiated, although the permeability of a laser beam 8 penetrates the firmly attached seat member 4 highly, the permeability of a laser beam 8 is inferior in the installation base 11 formed with acetal resin, and it causes absorption of a laser beam 8.

[0013] Then, although melting does not result, temperature rises (for example, the rise to about 100 degrees C can be considered), the firmly attached seat member 4 is also heated by this heating, the firmly attached seat member 4 pastes the installation base 11, and it becomes impossible for the part where the laser beam 8 of the installation base 11 was irradiated to remove the firmly attached seat member 4 easily from laser-beam-machining equipment, and it changes with causes, such as damage on the semi-conductor wafer 3. [0014] Moreover, in order to perform vacuum adsorption, dust etc. invades in the hole 10 for adsorption formed in the installation base 11, a laser beam 8 is irradiated, is heated by that dust, the firmly attached seat member 4 is heated by this heating, and it is possible to produce the same phenomenon as the abovementioned case.

[0015]

[Problem(s) to be Solved by the Invention] When it was constituted as mentioned above, the firmly attached seat member 4 pasted the installation base 11 and conventional laser-beam-machining equipment removed the semi-conductor wafer 3 of a workpiece from laser-beam-machining equipment, the semi-conductor wafer 3 was damaged and it had the trouble that quality deteriorated. Moreover, when the firmly attached seat member 4 was fixed on the installation base 11 by vacuum adsorption, since the whole surface of the firmly attached seat member 4 touched on the installation base 11, balking of the firmly attached seat member 4 became difficult from the installation base 11, and after vacuum disconnection damaged the semi-conductor wafer 3, and had the trouble that quality deteriorated.

[0016] This invention aims at offering the laser-beam-machining equipment which can detach and attach a workpiece easily, without having been made in order to cancel the above troubles, and reducing the quality of a workpiece.

[0017]

[Means for Solving the Problem] The laser-beam-machining equipment of claim 1 concerning this invention The firmly attached seat member which changes with the quality of the material which pastes up the workpiece which has the part which absorbs a laser beam, and is fixed, and penetrates a laser beam, In the laser-beam-machining equipment which is equipped with the installation base which lays a firmly attached seat member and is fixed, irradiates a laser beam at a workpiece, and melts a workpiece an installation base It is formed with the quality of the material in which an installation base and a firmly attached seat member touch, and the laser radiation section corresponding to the processing field of a workpiece penetrates a laser beam

[0018] Moreover, in claim 1, as for the laser-beam-machining equipment of claim 2 concerning this invention, the laser radiation section of an installation base is formed with glass, using an YAG laser as a laser beam.

[0019] Moreover, the laser-beam-machining equipment of claim 3 concerning this invention The firmly

[0024]

attached seat member which changes with the quality of the material which pastes up the workpiece which has the part which absorbs a laser beam, and is fixed, and penetrates a laser beam. In the laser-beam-machining equipment which is equipped with the installation base which lays a firmly attached seat member and is fixed, irradiates a laser beam at a workpiece, and melts a workpiece an installation base The laser radiation section which an installation base and a firmly attached seat member touch, and corresponds with the processing field of a workpiece is formed with the quality of the material which reflects a laser beam.

[0020] Moreover, in claim 3, as for the laser-beam-machining equipment of claim 4 concerning this invention, the laser radiation section of an installation base is formed with copper, gold, or aluminum, using an YAG laser as a laser beam.

[0021] Moreover, the laser-beam-machining equipment of claim 5 concerning this invention is equipped with the firmly attached seat member which pastes up the workpiece which has the part which absorbs a laser beam, and is fixed, and the installation base which lay a firmly attached seat member and fixes by vacuum adsorption, and the hole for adsorption for carrying out vacuum adsorption of the firmly attached seat member of an installation base is formed in the outside of the processing field of a workpiece in the laser-beam-machining equipment which irradiates a laser beam at a workpiece and melts a workpiece. [0022] Moreover, the laser-beam-machining equipment of claim 6 concerning this invention deforms a firmly attached seat member along with the concave of an installation base at the time of vacuum adsorption by forming the upper part of an installation base in the concave of a reverse trapezoid, and equipping the periphery section of a concave pars basilaris ossis occipitalis with the hole for adsorption in claim 5, and vacuum adsorption is carried out on an installation base.

[0023] Moreover, the laser-beam-machining equipment of claim 7 concerning this invention The firmly attached seat member which pastes up the workpiece which has the part which absorbs a laser beam, and is fixed, In the laser-beam-machining equipment which is equipped with the installation base which lays a firmly attached seat member and is fixed by vacuum adsorption, irradiates a laser beam at a workpiece, and melts a workpiece The hole for adsorption is equipped with the pressurization means to which the atmospheric pressure more than atmospheric pressure is applied at the time of balking of the firmly attached seat member from the hole for adsorption and installation base for carrying out vacuum adsorption of the firmly attached seat member of an installation base.

[Embodiment of the Invention] The gestalt of implementation of this invention is explained below gestalt 1. of operation. Drawing in which drawing 1 shows the configuration of the laser-beam-machining equipment of the gestalt 1 of operation of this invention, and drawing 2 are drawings for explaining the processing approach using the laser-beam-machining equipment shown in drawing 1. In drawing 1, it is the installation base where 16 was formed in the body of laser-beam-machining equipment, and 17 was formed on this body 16, and is formed with the quality of the material which penetrates a laser beam. [0025] 18 is the firmly attached seat member which pastes up the semi-conductor wafer 19 as a workpiece which has the part which absorbs a laser beam, and is fixed, and one side is formed in a glue line and it changes with the quality of the material which penetrates a laser beam. A fixed jig for the stop ring for holding 20, where the perimeter of the firmly attached seat member 18 is pulled, and 21 to stick the firmly attached seat member 18 and the top face of the installation base 17, and 22 are the holes for adsorption established in the installation base 17, and are for performing vacuum adsorption with the installation base 17 and the firmly attached seat member 18. [many]

[0026] The pressurization means to which the atmospheric pressure more than atmospheric pressure is applied, and 27 are the 2nd bulb for opening and closing this pressurization means 26 by a vacuum gage for the 1st bulb for the vacuum pump which 23 opens for free passage in the hole 22 for adsorption, and 24 opening and closing this vacuum pump 23, and 25 checking the negative pressure by the vacuum pump 23, and 26 being opened for free passage by the hole 22 for adsorption, for example, supplying desiccation Ayr to this adsorption hole 22.

[0027] In drawing 2, it is the part to which 28 is connected to with a semiconductor device and 29 is connected between each semiconductor device 28 and which absorbs a laser beam, for example, the semiconductor wafer 19 as a workpiece is constituted by the metal section which changes with nickel excellent in absorption of a laser beam, these semiconductor devices 28, and the metal section 29. 30 is a laser beam for processing a workpiece. Here, suppose that the quartz glass which was excellent in the permeability of an YAG laser considering the YAG laser (that whose wavelength is 1.06 micrometers) as an installation

base 17 is used as a laser beam 30, respectively.

[0028] Next, the processing approach of the laser-beam-machining equipment of the gestalt 1 the operation constituted as mentioned above is explained. First, like the conventional case, the semi-conductor wafer 19 is pasted up on the firmly attached seat member 18, and it fixes (drawing 2 (a)). Next, the firmly attached seat member 18 is laid on the installation base 17. Next, after the stop ring 20 has pulled the perimeter of the firmly attached seat member 18, it holds.

[0029] Next, it presses down with the fixed jig 21 from the top face around the firmly attached seat member 18, and the perimeter of the firmly attached seat member 18 and the top face of the installation base 17 are stuck. Next, opening the 1st bulb 24 wide, operating a vacuum pump 23, and checking with the vacuum gage 25, desired negative pressure is applied from the hole 22 for adsorption, and the installation base 17 is made to carry out vacuum adsorption of the firmly attached seat member 18.

[0030] Next, a laser beam 30 is irradiated with a desired beam diameter at the metal section 29 of the semi-conductor wafer 19, maintaining this condition (<u>drawing 2</u>(b)). Under the present circumstances, although a laser beam 30 is irradiated by the firmly attached seat member 18 and the installation base 17, temperature does not rise and the firmly attached seat member 18 and the installation base 17 are not pasted [each other] up in order to penetrate a laser beam 30.

[0031] And a dissolution part melts with surface tension, the metal section 29 separates, is carried out [a laser beam 30 is absorbed, temperature rises melting is carried out,], the dissolution coagulation section 31 is formed, and each semiconductor device 28 is separated (drawing 2 (c)). Next, while closing the 1st bulb 24, actuation of a vacuum pump 23 is suspended. Next, the 2nd bulb 26 is opened wide, desiccation Ayr is supplied to the hole 22 for adsorption from the pressurization means 26, and the pressure more than atmospheric pressure (for example, 1.5 atmospheric-pressure extent is assumed) is put. And it is made to secede from the firmly attached seat member 18 automatically from the installation base 17.

[0032] Next, the firmly attached seat member 18 is pulled and lengthened, between each separated semiconductor device 28 is extended, and each semiconductor device 28 is removed from the firmly attached seat member 18.

[0033] According to the laser-beam-machining equipment of the gestalt 1 of the operation formed as mentioned above, at the time of laser beam machining, since a laser beam 30 is penetrated and such temperature hardly rises, the firmly attached seat member 18 and the installation base 17 do not paste up the firmly attached seat member 18 and the installation base 17. Therefore, it can secede from the firmly attached seat member 18 easily from laser-beam-machining equipment, without doing damage to the semi-conductor wafer 19 after processing.

[0034] Moreover, since the firmly attached seat member 18 secedes from the installation base 17 automatically by putting the pressure more than atmospheric pressure from the hole 22 for adsorption in the case of the balking, it can be made to secede from the firmly attached seat member 18 still more easily from laser-beam-machining equipment.

[0035] There is no ******. in addition, in the gestalt 1 of the above-mentioned implementation, although the example which forms all the installation bases 17 with the quality of the material which has the permeability of a laser beam was shown, restrict to this -- If formed with the quality of the material in which the installation base 17 and the firmly attached seat member 18 touch among the installation bases 17 at least, and the laser radiation section corresponding to the processing field of the semi-conductor wafer 19 penetrates a laser beam 30 Cost is reducible, if to say nothing of doing so the same effectiveness as the gestalt 1 of the above-mentioned implementation only a required field is formed with glass when using [for example,] the expensive quality of the materials, such as glass.

[0036] Although the gestalt 1 of the gestalt 2. above-mentioned implementation of operation showed the example formed with the quality of the material in which the installation base 17 penetrates a laser beam 30, even if it forms an installation base with the quality of the material which reflects a laser beam, the same effectiveness as the gestalt 1 of the above-mentioned implementation can be done so.

[0037] <u>Drawing 3</u> is drawing having shown the part and its processing approach of the laser-beam-machining equipment in the gestalt 2 of implementation of this invention. In drawing, the same part as the gestalt 1 of the above-mentioned implementation attaches the same sign, and omits explanation. A laser beam for 32 to process the semi-conductor wafer 19 as a workpiece and 33 are the installation bases for laying the firmly attached seat member 18, and are formed with the quality of the material which reflects a laser beam. 32a is the reflected light which the laser beam 32 reflected on the installation base 33. Here, the

installation base 33 shall form an YAG laser as a laser beam 32 with copper excellent in reflection of an YAG laser, gold, or aluminum.

[0038] Next, the processing approach of the laser-beam-machining equipment of the gestalt 2 the operation constituted as mentioned above is explained. First, like the gestalt 1 of the above-mentioned implementation, after making the installation base 33 carry out vacuum adsorption of the firmly attached seat member 18, as shown in drawing 3 (a), a laser beam 32 is irradiated with a desired beam diameter at the metal section 29 of the semi-conductor wafer 19. Under the present circumstances, although a laser beam 30 is irradiated by the firmly attached seat member 18 and the installation base 33, the firmly attached seat member 18 penetrates a laser beam 32, on the installation base 33, a laser beam 32 reflects, and changes with reflected light 32a, and does not absorb a laser beam 32. Therefore, such temperature hardly rises and pasting up mutually is prevented.

[0039] Henceforth, it carries out by the same approach as the gestalt 1 of the above-mentioned implementation, and the metal section 29 absorbs a laser beam 32, temperature rises, and is dissolved, the dissolution coagulation section 31 is formed, and each semiconductor device 28 is separated (<u>drawing 3</u>) (b)). And it secedes from the installation base 33 from the firmly attached seat member 18, and each semiconductor device 28 is removed from the firmly attached seat member 18.

[0040] According to the gestalt 2 of the operation constituted as mentioned above, not to mention doing so the same effectiveness as the gestalt 1 of the above-mentioned implementation, that what is necessary is just to form with the quality of the material in which a laser beam 32 reflects the installation base 33, as compared with glass, it is easy to process copper, gold, or aluminum, and its worries about breakage decrease.

[0041] In addition, although the example formed in the gestalt 2 of the above-mentioned implementation with the quality of the material in which all the installation bases 33 reflect a laser beam 32 was shown, it is not restricted to this. If formed with the quality of the material in which the installation base 33 and the firmly attached seat member 18 touch among the installation bases 33 at least, and the laser radiation section corresponding to the processing field of the semi-conductor wafer 19 reflects a laser beam 32 The case where it changes with the quality of the material in which only the front face of the installation base 33 reflects a laser beam 32 to say nothing of doing so the same effectiveness as the gestalt 2 of the above-mentioned implementation etc. can be considered.

[0042] Gestalt 3. drawing 4 of operation is drawing showing the configuration and processing process of laser-beam-machining equipment of operation in this invention. [of a gestalt 3] In drawing, the same part as the gestalt of each above-mentioned implementation attaches the same sign, and omits explanation. It is possible that 34 is formed with the quality of the material which is the installation base which lays the firmly attached seat member 18 and is fixed by vacuum adsorption, for example, penetrates a laser beam, or the quality of the material which reflects a laser beam. The crevice of a reverse trapezoid where 34a was formed in the upper part of the installation base 34, and 35 are the hole for adsorption formed in the periphery section of the pars basilaris ossis occipitalis of crevice 34a of a reverse trapezoid while being formed in the outside of the processing field of the semi-conductor wafer 19.

[0043] Next, the processing process of the laser-beam-machining equipment of the gestalt 3 of the operation constituted as mentioned above is explained. First, the firmly attached seat member 18 is laid on the installation base 34 like the gestalt of each above-mentioned implementation (<u>drawing 4</u> (a)). Next, opening the 1st bulb 24 wide, operating a vacuum pump 23, and checking with the vacuum gage 25, desired negative pressure is applied from the hole 35 for adsorption, and the installation base 34 is made to carry out vacuum adsorption of the firmly attached seat member 18 (<u>drawing 4</u> (b)). Under the present circumstances, the firmly attached seat member 18 deforms into the configuration of crevice 34a of a reverse trapezoid of the top face of the installation base 34, and is adsorbed so that clearly also from <u>drawing 4</u> (b).

[0044] Thus, since the inside [hole / 35 / of the installation base 34 / for adsorption] is formed lower than an outside [hole / 36 / for adsorption], even if the hole 35 for adsorption is formed in the outside of the processing field of the semi-conductor wafer 19 of the installation base 34 in the case of vacuum adsorption, vacuum adsorption can be performed, without air bubbles remaining between the installation base 34 and the firmly attached seat member 18.

[0045] Next, the semi-conductor wafer 19 is processed in a laser beam like the gestalt of each abovementioned implementation. Under the present circumstances, since the hole 35 for adsorption is formed in the outside of the processing field of the semi-conductor wafer 19, a laser beam is not irradiated by the hole 35 for adsorption. Therefore, it is not heated even if dust etc. exists in the hole 35 for adsorption. [0046] Next, while closing the 1st bulb 24, actuation of a vacuum pump 23 is suspended (drawing 4 (a)). Then, the firmly attached seat member 18 separates from crevice 34a of a reverse trapezoid of the installation base 34, and returns to the original condition. And like the gestalt of each above-mentioned implementation, it secedes from the installation base 34 from the firmly attached seat member 18, and the semi-conductor wafer 19 is removed from the firmly attached seat member 18.

[0047] According to the gestalt 3 of the operation constituted as mentioned above, not to mention doing so the same effectiveness as the gestalt of each above-mentioned implementation, heating by the dust in the hole 35 for adsorption etc. is prevented, and the fault by the firmly attached seat member 18 being heated can be canceled.

[0048] In addition, in the gestalt of each above-mentioned implementation, although the example using a semi-conductor wafer as a workpiece was shown, things have the effectiveness excellent in that of which detailed processing is required needless to say especially that what is necessary is just the workpiece which has the part which is not restricted to this and absorbs a laser beam. Moreover, although the example which cuts between the semiconductor devices of a semi-conductor wafer was shown, to say nothing of things, the same effectiveness is done so that what is necessary is just processing which is not restricted to this, for example, uses fusing by laser beams, such as punching processing. Moreover, the atmospheric pressure more than atmospheric pressure is applied to the hole for adsorption for balking by vacuum adsorption with an installation base and a firmly attached seat member, and from an installation base, if it secedes from a firmly attached seat member as it floats, the damage to a workpiece can be prevented.

[0049]

[Effect of the Invention] As mentioned above, the firmly attached seat member which changes with the quality of the material which pastes up the workpiece which has the part which absorbs a laser beam according to claim 1 of this invention, and is fixed, and penetrates a laser beam, In the laser-beam-machining equipment which is equipped with the installation base which lays a firmly attached seat member and is fixed, irradiates a laser beam at a workpiece, and melts a workpiece an installation base Since it is formed with the quality of the material in which an installation base and a firmly attached seat member touch, and the laser radiation section corresponding to the processing field of a workpiece penetrates a laser beam It is prevented that an installation base is heated, it can secede from a sheet member easily from an installation base, and becomes possible [offering the laser-beam-machining equipment which can prevent damage on a workpiece].

[0050] Moreover, since it can perform certainly that an installation base penetrates a laser beam in claim 1 since the laser radiation section of an installation base is formed with glass, using an YAG laser as a laser beam according to claim 2 of this invention, it can secede from a sheet member easily from an installation base, and it becomes possible to offer the laser-beam-machining equipment which can prevent damage on a workpiece.

[0051] Moreover, the firmly attached seat member which becomes with the quality of the material which pastes up the workpiece which has the part which absorbs a laser beam according to claim 3 of this invention, and is fixed, and penetrates a laser beam, In the laser-beam-machining equipment which is equipped with the installation base which lays a firmly attached seat member and is fixed, irradiates a laser beam at a workpiece, and melts a workpiece an installation base Since the laser radiation section which an installation base and a firmly attached seat member touch, and corresponds with the processing field of a workpiece is formed with the quality of the material which reflects a laser beam It is prevented that an installation base is heated, it can secede from a sheet member easily from an installation base, and becomes possible [offering the laser-beam-machining equipment which can prevent damage on a workpiece]. [0052] Moreover, since it can perform certainly that an installation base reflects a laser beam in claim 3 since the laser radiation section of an installation base is formed with copper, gold, or aluminum, using an YAG laser as a laser beam according to claim 4 of this invention, it can secede from a sheet member easily from an installation base, and it becomes possible to offer the laser-beam-machining equipment which can prevent damage on a workpiece.

[0053] Moreover, the firmly attached seat member which pastes up the workpiece which has the part which absorbs a laser beam according to claim 5 of this invention, and is fixed, In the laser-beam-machining equipment which is equipped with the installation base which lays a firmly attached seat member and is fixed by vacuum adsorption, irradiates a laser beam at a workpiece, and melts a workpiece Since the hole for

adsorption for carrying out vacuum adsorption of the firmly attached seat member of an installation base is formed in the outside of the processing field of a workpiece Generating of heating from the hole for adsorption is prevented, it can secede from a sheet member easily from an installation base, and it becomes possible to offer the laser-beam-machining equipment which can prevent damage on a workpiece. [0054] According to claim 6 of this invention, it sets to claim 5. Moreover, the upper part of an installation base Since it is formed in the concave of a reverse trapezoid, the periphery section of a concave pars basilaris ossis occipitalis is equipped with the hole for adsorption, a firmly attached seat member deforms along with the concave of an installation base at the time of vacuum adsorption and vacuum-adsorption is carried out on an installation base It becomes possible to offer the laser-beam-machining equipment which can carry out vacuum adsorption of a firmly attached seat member and the installation base certainly. [0055] Moreover, the firmly attached seat member which pastes up the workpiece which has the part which absorbs a laser beam according to claim 7 of this invention, and is fixed, In the laser-beam-machining equipment which is equipped with the installation base which lays a firmly attached seat member and is fixed by vacuum adsorption, irradiates a laser beam at a workpiece, and melts a workpiece Since the hole for adsorption was equipped with the pressurization means to which the atmospheric pressure more than atmospheric pressure is applied at the time of balking of the firmly attached seat member from the hole for adsorption and installation base for carrying out vacuum adsorption of the firmly attached seat member of an installation base It becomes possible to offer the laser-beam-machining equipment which can secede from on an installation base from a firmly attached seat member easily.

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TECHNICAL FIELD

[Field of the Invention] A workpiece can be easily detached and attached from laser-beam-machining equipment, without starting laser-beam-machining equipment for this invention performing chip separation of the semiconductor device of a semi-conductor wafer as a workpiece, and reducing the quality of a workpiece.

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PRIOR ART

[Description of the Prior Art] Conventionally, as the chip separation approach of a semi-conductor wafer, there was a dance cut method by the diamond wheel. This approach is an approach one side sticks a wafer on the sheet-like ingredient which changes with adhesive tape, cuts a little sheet-like ingredient deeply, and cuts a wafer completely. However, by this approach, since there were many rates of the metallic material in the separation section, when the thickness of the separation section was set to 100 micrometers or less, there were metaled weld flash and a trouble that a crack occurred to a wafer.

[0003] As an approach for solving that, the method of performing chip separation of a semi-conductor wafer to JP,8-264491,A in a laser beam is proposed. <u>Drawing 5</u> R> 5 is drawing showing the chip separation approach of the semiconductor device in JP,8-264491,A. It is based on a Fig. below and the approach of chip separation of a semi-conductor wafer is explained.

[0004] First, when the semi-conductor wafer 3 as a workpiece connected, respectively in the metal section 2 of which between each semiconductor device 1 consists with nickel excellent in absorption of a laser beam is formed as shown in <u>drawing 5</u> (a) for example, this semi-conductor wafer 3 is pasted up on the adhesion side side of the firmly attached seat member 4 which has an adhesive property on one side, and it fixes (<u>drawing 5</u> (b)). Next, as shown in <u>drawing 6</u>, it is held after the stop ring 5 has pulled the perimeter of the firmly attached seat member 4, and the semi-conductor wafer 3 will be in the condition that it is held in the air.

[0005] And this stop ring 5 is being fixed to the body section 6 of laser-beam-machining equipment with the fixed jig 7. Next, a laser beam 8 is irradiated with a desired beam diameter at the metal section 2 of the semi-conductor wafer 3 (drawing 5 (c)). And a dissolution part melts with surface tension, the metal section 2 separates, is carried out [it fuses, and], the dissolution coagulation section 9 is formed, and each semiconductor device 1 is separated (drawing 5 (d)).

[0006] Then, the firmly attached seat member 4 is removed from laser-beam-machining equipment. Next, the firmly attached seat member 4 is pulled and lengthened, and between each separated semiconductor device 1 is extended. If it does in this way, each semiconductor device 1 can be easily removed from the firmly attached seat member 4.

[0007] If each semiconductor device 1 is separated as mentioned above, while irradiating the laser beam 8, the temperature of the semi-conductor wafer 3 rises and the location of elongation and the semi-conductor wafer 3 under processing moves [the firmly attached seat member 4] vertically and horizontally in connection with this. For this reason, focal gap of a laser beam 8 arose during processing, and there was a trouble that process tolerance fell.

[0008] In order to solve this, as shown in <u>drawing 8</u>, the installation base 11 equipped with many holes 10 for adsorption is formed on the body 6 of laser-beam-machining equipment, and the firmly attached seat member 4 to which the semi-conductor wafer 3 was fixed is laid on this installation base 11. Next, in order to stick the perimeter of the firmly attached seat member 4, and the top face of the installation base 11, it presses down with the fixed jig 12 from on the firmly attached seat member 4.

[0009] Next, opening wide the bulb 15 of the vacuum pump 13 which was open for free passage in the hole 10 for adsorption, and checking with the vacuum gage 14, desired negative pressure is applied from the hole 10 for adsorption with a vacuum pump 13, and the installation base 11 is made to carry out vacuum adsorption of the firmly attached seat member 4. Next, it is processed like the above-mentioned conventional case by the laser beam 8, maintaining this condition (<u>drawing 7</u> (a)). And a dissolution part melts with surface tension, the metal section 2 separates, is carried out [it fuses, and], the dissolution coagulation section 9 is formed, and each semiconductor device 1 is separated (<u>drawing 7</u> (b)).

[0010] Then, while stopping a vacuum pump 13, a bulb 15 is closed and it opens wide to atmospheric pressure, and vacuum adsorption is canceled, and the firmly attached seat member 4 is removed from laser-beam-machining equipment. Next, the firmly attached seat member 4 is pulled and lengthened, between each separated semiconductor device 1 is extended, and each semiconductor device 1 is removed from the firmly attached seat member 4.

[0011] If such laser-beam-machining equipment is used, since the solid-state sheet member 4 is fixed on the installation base 11, it is canceled and gap of the firmly attached seat member 4 at the time of the exposure of a laser beam 8 can perform processing excellent in precision.

[0012] Without damaging a laser beam 8, the quality of the material of the installation base 11 used here is excellent in process tolerance, and, generally can consider use of acetal resin from points, such as low cost. However, as shown in <u>drawing 9</u>, when a laser beam 8 is irradiated, although the permeability of a laser beam 8 penetrates the firmly attached seat member 4 highly, the permeability of a laser beam 8 is inferior in the installation base 11 formed with acetal resin, and it causes absorption of a laser beam 8.

[0013] Then, although melting does not result, temperature rises (for example, the rise to about 100 degrees C can be considered), the firmly attached seat member 4 is also heated by this heating, the firmly attached seat member 4 pastes the installation base 11, and it becomes impossible for the part where the laser beam 8 of the installation base 11 was irradiated to remove the firmly attached seat member 4 easily from laser-beam-machining equipment, and it changes with causes, such as damage on the semi-conductor wafer 3. [0014] Moreover, in order to perform vacuum adsorption, dust etc. invades in the hole 10 for adsorption formed in the installation base 11, a laser beam 8 is irradiated, is heated by that dust, the firmly attached seat member 4 is heated by this heating, and it is possible to produce the same phenomenon as the above-mentioned case.

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EFFECT OF THE INVENTION

[Effect of the Invention] As mentioned above, the firmly attached seat member which changes with the quality of the material which pastes up the workpiece which has the part which absorbs a laser beam according to claim 1 of this invention, and is fixed, and penetrates a laser beam, In the laser-beam-machining equipment which is equipped with the installation base which lays a firmly attached seat member and is fixed, irradiates a laser beam at a workpiece, and melts a workpiece an installation base Since it is formed with the quality of the material in which an installation base and a firmly attached seat member touch, and the laser radiation section corresponding to the processing field of a workpiece penetrates a laser beam It is prevented that an installation base is heated, it can secede from a sheet member easily from an installation base, and becomes possible [offering the laser-beam-machining equipment which can prevent damage on a workpiece].

[0050] Moreover, since it can perform certainly that an installation base penetrates a laser beam in claim 1 since the laser radiation section of an installation base is formed with glass, using an YAG laser as a laser beam according to claim 2 of this invention, it can secede from a sheet member easily from an installation base, and it becomes possible to offer the laser-beam-machining equipment which can prevent damage on a workpiece.

[0051] Moreover, the firmly attached seat member which becomes with the quality of the material which pastes up the workpiece which has the part which absorbs a laser beam according to claim 3 of this invention, and is fixed, and penetrates a laser beam, In the laser-beam-machining equipment which is equipped with the installation base which lays a firmly attached seat member and is fixed, irradiates a laser beam at a workpiece, and melts a workpiece an installation base Since the laser radiation section which an installation base and a firmly attached seat member touch, and corresponds with the processing field of a workpiece is formed with the quality of the material which reflects a laser beam It is prevented that an installation base is heated, it can secede from a sheet member easily from an installation base, and becomes possible [offering the laser-beam-machining equipment which can prevent damage on a workpiece]. [0052] Moreover, since it can perform certainly that an installation base reflects a laser beam in claim 3 since the laser radiation section of an installation base is formed with copper, gold, or aluminum, using an YAG laser as a laser beam according to claim 4 of this invention, it can secede from a sheet member easily from an installation base, and it becomes possible to offer the laser-beam-machining equipment which can prevent damage on a workpiece.

[0053] Moreover, the firmly attached seat member which pastes up the workpiece which has the part which absorbs a laser beam according to claim 5 of this invention, and is fixed, In the laser-beam-machining equipment which is equipped with the installation base which lays a firmly attached seat member and is fixed by vacuum adsorption, irradiates a laser beam at a workpiece, and melts a workpiece Since the hole for adsorption for carrying out vacuum adsorption of the firmly attached seat member of an installation base is formed in the outside of the processing field of a workpiece Generating of heating from the hole for adsorption is prevented, it can secede from a sheet member easily from an installation base, and it becomes possible to offer the laser-beam-machining equipment which can prevent damage on a workpiece.

[0054] According to claim 6 of this invention, it sets to claim 5. Moreover, the upper part of an installation base Since it is formed in the concave of a reverse trapezoid, the periphery section of a concave pars basilaris ossis occipitalis is equipped with the hole for adsorption, a firmly attached seat member deforms along with the concave of an installation base at the time of vacuum adsorption and vacuum adsorption is carried out on an installation base It becomes possible to offer the laser-beam-machining equipment which can carry out vacuum adsorption of a firmly attached seat member and the installation base certainly.

[0055] Moreover, the firmly attached seat member which pastes up the workpiece which has the part which absorbs a laser beam according to claim 7 of this invention, and is fixed, In the laser-beam-machining equipment which is equipped with the installation base which lays a firmly attached seat member and is fixed by vacuum adsorption, irradiates a laser beam at a workpiece, and melts a workpiece Since the hole for adsorption was equipped with the pressurization means to which the atmospheric pressure more than atmospheric pressure is applied at the time of balking of the firmly attached seat member from the hole for adsorption and installation base for carrying out vacuum adsorption of the firmly attached seat member of an installation base It becomes possible to offer the laser-beam-machining equipment which can secede from on an installation base from a firmly attached seat member easily.

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TECHNICAL PROBLEM

[Problem(s) to be Solved by the Invention] When it was constituted as mentioned above, the firmly attached seat member 4 pasted the installation base 11 and conventional laser-beam-machining equipment removed the semi-conductor wafer 3 of a workpiece from laser-beam-machining equipment, the semi-conductor wafer 3 was damaged and it had the trouble that quality deteriorated. Moreover, when the firmly attached seat member 4 was fixed on the installation base 11 by vacuum adsorption, since the whole surface of the firmly attached seat member 4 touched on the installation base 11, balking of the firmly attached seat member 4 became difficult from the installation base 11, and after vacuum disconnection damaged the semi-conductor wafer 3, and had the trouble that quality deteriorated.

[0016] This invention aims at offering the laser-beam-machining equipment which can detach and attach a workpiece easily, without having been made in order to cancel the above troubles, and reducing the quality of a workpiece.

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DESCRIPTION OF DRAWINGS

[Brief Description of the Drawings]

[Drawing 1] It is drawing showing the configuration of the laser-beam-machining equipment by the gestalt 1 of implementation of this invention.

[Drawing 2] It is drawing showing the processing approach of the laser-beam-machining equipment shown in drawing 1.

[Drawing 3] It is drawing showing the processing approach of the laser-beam-machining equipment by the gestalt 2 of implementation of this invention.

[Drawing 4] It is drawing showing the configuration of the laser-beam-machining equipment by the gestalt 3 of implementation of this invention.

[Drawing 5] It is drawing showing the processing approach of conventional laser-beam-machining equipment.

[Drawing 6] It is drawing showing the configuration of the conventional laser-beam-machining equipment used in drawing 5.

[Drawing 7] It is drawing showing the processing approach of other conventional laser-beam-machining equipments.

[Drawing 8] It is drawing showing the configuration of the conventional laser-beam-machining equipment used in drawing 7.

[Drawing 9] It is drawing for explaining the trouble of other conventional laser-beam-machining equipments.

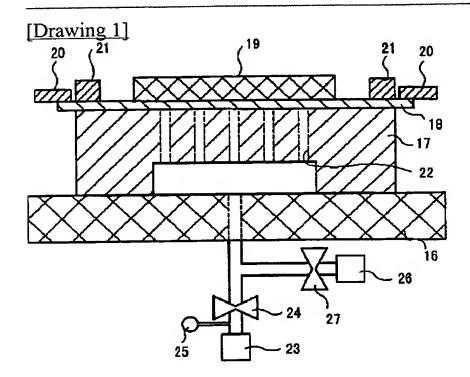
[Description of Notations]

16 Body, 17, 33, 34 Installation Base, 18 Firmly Attached Seat Member, 19 A semi-conductor wafer, 20 A stop ring, 21 22 A fixed jig, 35 The hole for adsorption, 23 A vacuum pump, 24 The 1st bulb, 25 A vacuum gage, 26 A pressurization means, 27 The 2nd bulb, 28 A semiconductor device, 29 The metal section, 30 A laser beam, 31 The dissolution coagulation section, 32 A laser beam, 32a The reflected light, 34a Reverse trapezoid crevice.

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DRAWINGS



16:本体

22:吸着用穴

17: 載置台

23:真空ポンプ

18: 固定シート部材

24:第1のパルブ

19: 半導体ウエハ

25: 真空ゲージ

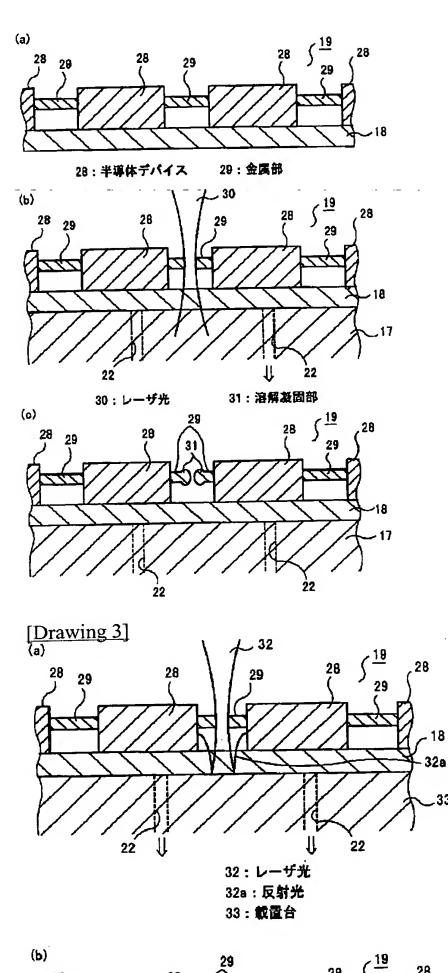
20: 固定リング

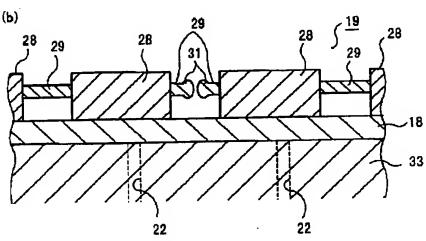
26:加圧手段

21: 固定治具

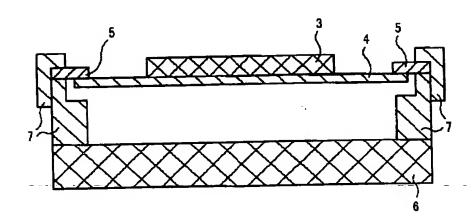
27:第2のパルブ

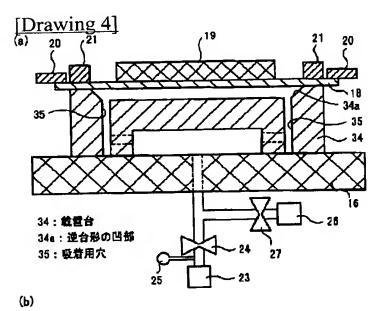
[Drawing 2]

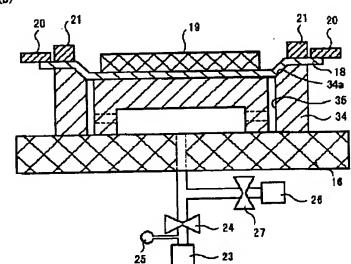




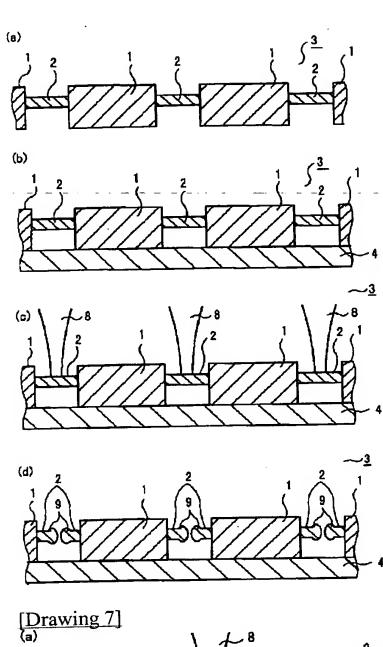
[Drawing 6]

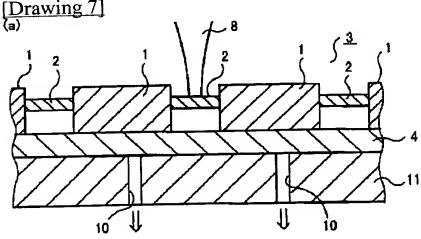


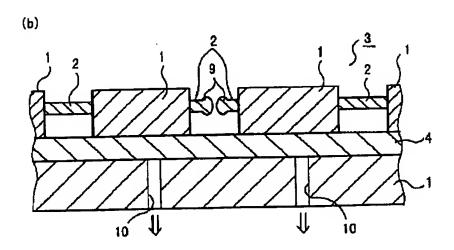




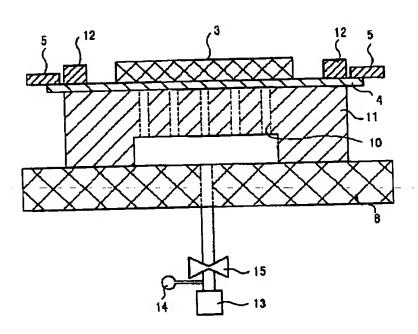
[Drawing 5]

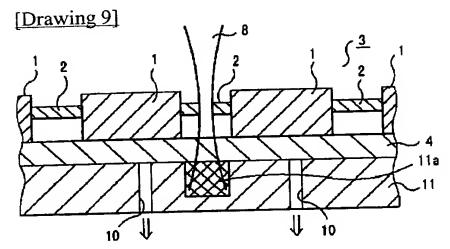






[Drawing 8]





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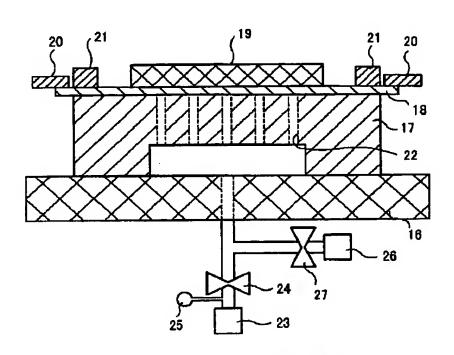
最終頁に続く

(54) 【発明の名称】 レーザ加工装置

(57)【要約】

【課題】 被加工物の品質を低下させることなく、被加 工物をレーザ加工装置から容易に着脱することができる レーザ加工装置を得ることを目的とする。

【解決手段】 レーザ光30を吸収する部分を有する半 導体ウエハ19を接着して固定し、かつ、レーザ光30 を透過する材質にて成る固定シート部材18と、固定シ ート部材18を載置して固定する載置台17とを備え、 半導体ウエハ19にレーザ光30を照射して被加工物を 溶断するレーザ加工装置において、載置台17は、レー ザ光30を透過する材質にて形成されている。



16: 本怀

22:吸着用穴

17: 載置台

23: 真空ポンプ

18: 固定シート部材

24:第1のパルブ

19:半導体ウエハ

25: 真空ゲージ 28:加圧手段

27: 第2のパルブ

20: 固定リング 21: 固定治具

【特許請求の範囲】

【請求項1】 レーザ光を吸収する部分を有する被加工物を接着して固定し、かつ、上記レーザ光を透過する材質にて成る固定シート部材と、上記固定シート部材を載置して固定する載置台とを備え、上記被加工物に上記レーザ光を照射して上記被加工物を溶断するレーザ加工装置において、上記載置台は、上記載置台と上記固定シート部材とが接し、かつ、上記被加工物の加工領域に対応するレーザ照射部が、上記レーザ光を透過する材質にて形成されていることを特徴とするレーザ加工装置。

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【請求項2】 レーザ光としてYAGレーザを用い、載置台のレーザ照射部がガラスにて形成されていることを特徴とする請求項1に記載のレーザ加工装置。

【請求項3】 レーザ光を吸収する部分を有する被加工物を接着して固定し、かつ、上記レーザ光を透過する材質にて成る固定シート部材と、上記固定シート部材を載置して固定する載置台とを備え、上記被加工物に上記レーザ光を照射して上記被加工物を溶断するレーザ加工装置において、上記載置台は、上記載置台と上記固定シート部材とが接し、かつ、上記被加工物の加工領域と対応するレーザ照射部が、上記レーザ光を反射する材質にて形成されていることを特徴とするレーザ加工装置。

【請求項4】 レーザ光としてYAGレーザを用い、載置台のレーザ照射部が銅、または、金、または、アルミニウムにて形成されていることを特徴とする請求項3に記載のレーザ加工装置。

【請求項5】 レーザ光を吸収する部分を有する被加工物を接着して固定する固定シート部材と、上記固定シート部材を載置して真空吸着にて固定する載置台とを備え、上記被加工物に上記レーザ光を照射して上記被加工 30物を溶断するレーザ加工装置において、上記載置台の上記固定シート部材を真空吸着するための吸着用穴が、上記被加工物の加工領域の外側に形成されていることを特徴とするレーザ加工装置。

【請求項6】 載置台の上部は、逆台形の凹状にて形成され、吸着用穴を上記凹状の底部の周縁部に備え、真空吸着時に、固定シート部材が上記載置台の凹状に沿って変形して上記載置台上に真空吸着されることを特徴とする請求項5に記載のレーザ加工装置。

【請求項7】 レーザ光を吸収する部分を有する被加工 40 物を接着して固定する固定シート部材と、上記固定シート部材を載置して真空吸着にて固定する載置台とを備え、上記被加工物に上記レーザ光を照射して上記被加工物を溶断するレーザ加工装置において、上記載置台の上記固定シート部材を真空吸着するための吸着用穴と、上記載置台からの上記固定シート部材の離脱時に、上記吸着用穴に大気圧以上の気圧をかける加圧手段を備えたことを特徴とするレーザ加工装置。

【発明の詳細な説明】

[0001]

【発明の属する技術分野】この発明は、例えば被加工物として半導体ウエハの半導体デバイスのチップ分離を行うためのレーザ加工装置に係り、被加工物の品質を低下させることなく、被加工物をレーザ加工装置から容易に着脱することができるものである。

-[-0-0-0-2-]- - - - - - - - -

【従来の技術】従来、半導体ウエハのチップ分離方法としては、ダイアモンドホイールによるダンシングカット方式があった。この方法は、片面が粘着テープで成るシート状材料にウエハを貼り付け、シート状材料を少し切り込んで、ウエハを完全に切断する方法である。しかし、この方法では、分離部での金属材料の割合が多いため、分離部の厚みが100μm以下となると、金属のバリや、ウエハにクラックが発生するという問題点があった。

【0003】そのことを解決するための方法として、例えば特開平8-264491号公報にレーザ光にて半導体ウエハのチップ分離を行う方法が提案されている。図5は特開平8-264491号公報における半導体デバイスのチップ分離方法を示す図である。以下図に基づいて、半導体ウエハのチップ分離の方法を説明する。

【0004】まず、図5 (a)に示すように、例えば各 半導体デバイス1間が、レーザ光の吸収に優れたニッケ ルにて成る金属部2にて、それぞれ接続された被加工物 としての半導体ウエハ3が形成されている場合、この半 導体ウエハ3を、片面に接着性を有する固定シート部材 4の接着面側に接着させて固定する(図5 (b))。次 に、図6に示すように、固定リング5にて、固定シート 部材4の周囲を引っ張った状態にて保持され、半導体ウ エハ3は空中に保持されるような状態となる。

【0005】そして、この固定リング5はレーザ加工装置の本体部6に、固定冶具7にて固定されている。次に、半導体ウエハ3の金属部2に所望のビーム径にてレーザ光8を照射する(図5(c))。そして、金属部2は溶融し、表面張力により溶解箇所が溶け別れして、溶解凝固部9が形成され、各半導体デバイス1は分離される(図5(d))。

【0006】その後、固定シート部材4をレーザ加工装置から取り外す。次に、固定シート部材4を引っ張って伸ばし、分離された各半導体デバイス1間を広げる。このようにすれば、各半導体デバイス1を固定シート部材4から容易に取り外すことができる。

【0007】上記のようにして各半導体デバイス1を分離すると、レーザ光8を照射している間に、半導体ウエハ3の温度が上昇し、これにともない固定シート部材4が伸び、加工中の半導体ウエハ3の位置が上下左右に移動する。このため、加工中にレーザ光8の焦点ズレが生じてしまい、加工精度が低下するという問題点があった。

50 【0008】このことを解決するために、図8に示すよ

うに、レーザ加工装置の本体6上に、吸着用穴10を多数備えた載置台11を設け、この載置台11上に、半導体ウエハ3が固定された固定シート部材4を載置する。 次に、固定シート部材4の周囲と載置台11の上面とを密着させるため、固定シート部材4上から固定冶具12にて押さえつける。

【0009】次に、吸着用穴10に連通した真空ポンプ13のバルブ15を開放して、真空ゲージ14にて確認しながら、真空ポンプ13にて吸着用穴10から所望の負圧をかけ、載置台11に固定シート部材4を真空吸着させる。次にこの状態を保ちながら、レーザ光8にて上記従来の場合と同様に加工を行う(図7(a))。そして、金属部2は溶融し、表面張力により溶解箇所が溶け別れして、溶解凝固部9が形成され、各半導体デバイス1は分離される(図7(b))。

【0010】その後、真空ポンプ13を止めるとともにバルブ15を閉じ大気圧まで開放し、真空吸着を解除して、固定シート部材4をレーザ加工装置から取り外す。次に、固定シート部材4を引っ張って伸ばし、分離された各半導体デバイス1間を広げて、各半導体デバイス1を固定シート部材4から取り外す。

【0011】このようなレーザ加工装置を用いれば、固体シート部材4は載置台11上に固定されるため、レーザ光8の照射時の固定シート部材4のズレは解消され、精度に優れた加工を行うことができる。

【0012】ここで使用される載置台11の材質は、レーザ光8に損傷されることなく、加工精度に優れ、低コストなどの点から、一般的にアセタール樹脂の使用が考えられる。しかし、図9に示すように、レーザ光8を照射した場合、固定シート部材4はレーザ光8の透過率が高く透過するものの、アセタール樹脂にて形成された載置台11はレーザ光8の透過率が劣り、レーザ光8の吸収をおこす。

【0013】すると、載置台11のレーザ光8が照射された箇所は、溶融までは至らないものの、温度が上昇し(例えば100℃程度までの上昇が考えられる)、この加熱により固定シート部材4も加熱され、載置台11に固定シート部材4が接着してしまい、固定シート部材4をレーザ加工装置から容易に外せなくなり、半導体ウエハ3の損傷などの原因と成る。

【0014】また、真空吸着を行うために、載置台11 に形成された吸着用穴10内にゴミなどが侵入し、その ゴミにレーザ光8が照射され、加熱されて、この加熱に より固定シート部材4が加熱され、上記場合と同様の現 象を生じることが考えられる。

[0015]

【発明が解決しようとする課題】従来のレーザ加工装置は上記のように構成され、載置台11に固定シート部材4が接着してしまい、レーザ加工装置から被加工物の半導体ウエハ3を取り外す際に、半導体ウエハ3が損傷し

品質が低下するという問題点があった。又、真空吸着に て載置台11上に固定シート部材4を固定すると、真空 開放後も載置台11上に固定シート部材4の全面が接触 しているため、載置台11から固定シート部材4の離脱 が困難となり、半導体ウエハ3を損傷してしまい品質が 低下するという問題点があった。-----

【0016】この発明は上記のような問題点を解消するためなされたもので、被加工物の品質を低下させることなく、被加工物を容易に着脱することができるレーザ加工装置を提供することを目的とする。

[0017]

【課題を解決するための手段】この発明に係る請求項1のレーザ加工装置は、レーザ光を吸収する部分を有する被加工物を接着して固定し、かつ、レーザ光を透過する材質にて成る固定シート部材と、固定シート部材を載置して固定する載置台とを備え、被加工物にレーザ光を照射して被加工物を溶断するレーザ加工装置において、載置台は、載置台と固定シート部材とが接し、かつ、被加工物の加工領域に対応するレーザ照射部が、レーザ光を透過する材質にて形成されているものである。

【0018】また、この発明に係る請求項2のレーザ加工装置は、請求項1において、レーザ光としてYAGレーザを用い、載置台のレーザ照射部がガラスにて形成されているものである。

【0019】また、この発明に係る請求項3のレーザ加工装置は、レーザ光を吸収する部分を有する被加工物を接着して固定し、かつ、レーザ光を透過する材質にて成る固定シート部材と、固定シート部材を載置して固定する載置台とを備え、被加工物にレーザ光を照射して被加工物を溶断するレーザ加工装置において、載置台は、載置台と固定シート部材とが接し、かつ、被加工物の加工領域と対応するレーザ照射部が、レーザ光を反射する材質にて形成されているものである。

工装置は、請求項3において、レーザ光としてYAGレーザを用い、載置台のレーザ照射部が銅、または、金、または、アルミニウムにて形成されているものである。【0021】また、この発明に係る請求項5のレーザ加工装置は、レーザ光を吸収する部分を有する被加工物を接着して固定する固定シート部材と、固定シート部材を載置して真空吸着にて固定する載置台とを備え、被加工物にレーザ光を照射して被加工物を溶断するレーザ加工装置において、載置台の固定シート部材を真空吸着する

【0020】また、この発明に係る請求項4のレーザ加

【0022】また、この発明に係る請求項6のレーザ加工装置は、請求項5において、載置台の上部は、逆台形の凹状にて形成され、吸着用穴を凹状の底部の周縁部に備え、真空吸着時に、固定シート部材が載置台の凹状に沿って変形して載置台上に真空吸着されるものである。

ための吸着用穴が、被加工物の加工領域の外側に形成さ

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50 沿って変形して載置台上に具

れているものである。

【0023】また、この発明に係る請求項7のレーザ加 工装置は、レーザ光を吸収する部分を有する被加工物を 接着して固定する固定シート部材と、固定シート部材を 載置して真空吸着にて固定する載置台とを備え、被加工 物にレーザ光を照射して被加工物を溶断するレーザ加工 装置において、載置台の固定シート部材を真空吸着する ための吸着用穴と、載置台からの固定シート部材の離脱 時に、吸着用穴に大気圧以上の気圧をかける加圧手段を 備えたものである。

[0024]

【発明の実施の形態】実施の形態1. 以下、この発明の 実施の形態について説明する。図1はこの発明の実施の 形態1のレーザ加工装置の構成を示す図、図2は図1に 示したレーザ加工装置を用いた加工方法を説明するため の図である。図1において、16はレーザ加工装置の本 体、17はこの本体16上に形成された載置台で、レー ザ光を透過する材質にて形成されている。

【0025】18はレーザ光を吸収する箇所を有する被 加工物としての半導体ウエハ19を接着して固定する固 定シート部材で、片面が接着層にて形成され、レーザ光 を透過する材質にて成る。20は固定シート部材18の 周囲を引っ張った状態にて保持するための固定リング、 21は固定シート部材18と載置台17の上面とを密着 させるための固定冶具、22は載置台17に多数設けら れた吸着用穴で、載置台17と固定シート部材18との 真空吸着を行うためのものである。

【0026】23は吸着用穴22に連通する真空ポン プ、24はこの真空ポンプ23の開閉を行うための第1 のバルブ、25は真空ポンプ23による負圧を確認する ための真空ゲージ、26は吸着用穴22に連通され、例 えばこの吸着穴22に乾燥エアーを供給することによ り、大気圧以上の気圧をかける加圧手段、27はこの加 圧手段26の開閉を行うための第2のバルブである。

【0027】図2において、28は半導体デバイス、2 9は各半導体デバイス28間にて接続されている、レー ザ光を吸収する部分であり、例えばレーザ光の吸収に優 れたニッケルにて成る金属部、これら半導体デバイス2 8および金属部29により被加工物としての半導体ウエ ハ19は構成されている。30は被加工物を加工するた めのレーザ光である。ここではレーザ光30としてYA Gレーザ (波長が1.06μmのもの)を、載置台17 としてYAGレーザの透過性に優れた石英ガラスをそれ ぞれ用いることとする。

【0028】次に上記のように構成された実施の形態1 のレーザ加工装置の加工方法について説明する。まず、 従来の場合と同様に、半導体ウエハ19を固定シート部 材18に接着させて固定する(図2(a))。次に、固 定シート部材18を載置台17上に載置する。次に、固 定リング20にて、固定シート部材18の周囲を引っ張 った状態にて保持する。

【0029】次に、固定シート部材18の周囲の上面か ら固定冶具21にて押さえつけ、固定シート部材18の 周囲と載置台17の上面とを密着させる。次に、第1の バルブ24を開放して真空ポンプ23を作動させ、真空 ゲージ25にて確認しながら、吸着用穴22から所望の 負圧をかけ、載置台17に固定シート部材18を真空吸 着させる。

【0030】次に、この状態を保ちながら、半導体ウエ ハ19の金属部29に所望のビーム径にてレーザ光30 10 を照射する(図2(b))。この際、固定シート部材1 8および載置台17にはレーザ光30が照射されるもの の、固定シート部材18および載置台17はレーザ光3 0を透過するため、温度が上昇することはなく、互いに 接着することはない。

【0031】そして、金属部29はレーザ光30を吸収 して温度が上昇して溶融され、表面張力により溶解箇所 が溶け別れして、溶解凝固部31が形成され、各半導体 デバイス28は分離される(図2(c))。次に、第1 のバルブ24を閉じるとともに、真空ポンプ23の動作 を停止する。次に、第2のバルブ26を開放し、吸着用 穴22に加圧手段26から乾燥エアーを供給して、大気 圧以上の圧力(例えば、1.5気圧程度が想定される) をかける。そして、固定シート部材18を載置台17か ら自動的に離脱させる。

【0032】次に、固定シート部材18を引っ張って伸 ばし、分離された各半導体デバイス28間を広げ、各半 導体デバイス28を固定シート部材18から取り外す。

【0033】上記のように形成された実施の形態1のレ ーザ加工装置によれば、レーザ加工時に、固定シート部 材18および載置台17はレーザ光30を透過し、これ らの温度がほとんど上昇しないため、固定シート部材1 8と載置台17とが接着することがない。よって、加工 後に、半導体ウエハ19に損傷を与えることなく、固定 シート部材18をレーザ加工装置から容易に離脱するこ とができる。

【0034】また、その離脱の際に、吸着用穴22から 大気圧以上の圧力をかけることにより、自動的に固定シ ート部材18は載置台17から離脱するため、固定シー ト部材18をレーザ加工装置からより一層容易に離脱さ せることができる。

【0035】尚、上記実施の形態1においては、載置台 17の全てをレーザ光の透過性を有する材質にて形成す る例を示したがこれに限れることはなく、少なくとも載 置台17のうち、載置台17と固定シート部材18とが 接し、かつ、半導体ウエハ19の加工領域に対応するレ ーザ照射部が、レーザ光30を透過する材質にて形成さ れていれば、上記実施の形態1と同様の効果を奏するこ とは言うまでもなく、例えばガラスなど高価な材質を利 用する場合、必要な領域のみガラスにて形成するように

50 すれば、コストを削減することができる。

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【0036】実施の形態2.上記実施の形態1では、載置台17がレーザ光30を透過する材質にて形成される例を示したが、載置台を、レーザ光を反射する材質にて形成するようにしても、上記実施の形態1と同様の効果を奏することができる。

【0037】図3はこの発明の実施の形態2におけるレーザ加工装置の一部とその加工方法を示した図である。図において、上記実施の形態1と同様の部分は同一符号を付して説明を省略する。32は被加工物としての半導体ウエハ19を加工するためのレーザ光、33は固定シート部材18を載置するための載置台で、レーザ光を反射する材質にて形成されている。32aは載置台33上にてレーザ光32としてYAGレーザを、載置台33はYAGレーザの反射に優れた銅、または、金、または、アルミニウムにて形成するものとする。

【0038】次に上記のように構成された実施の形態2のレーザ加工装置の加工方法について説明する。まず、上記実施の形態1と同様に、固定シート部材18を載置台33に真空吸着させた後、図3(a)に示したように、半導体ウエハ19の金属部29に所望のビーム径にてレーザ光32を照射する。この際、固定シート部材18および載置台33にはレーザ光30が照射されるものの、固定シート部材18はレーザ光32を透過し、載置台33上ではレーザ光32が反射し、反射光32aと成り、レーザ光32を吸収しない。よって、これらの温度が上昇することはほとんどなく、互いに接着するのは防止される。

【0039】以後、上記実施の形態1と同様の方法にて行い、金属部29はレーザ光32を吸収して温度が上昇して溶解され、溶解凝固部31が形成され、各半導体デバイス28は分離される(図3(b))。そして、固定シート部材18を載置台33から離脱し、固定シート部材18から各半導体デバイス28を取り外す。

【0040】上記のように構成された実施の形態2によれば、上記実施の形態1と同様の効果を奏するのはもちろんのこと、載置台33をレーザ光32が反射する材質にて形成すればよく、銅または金またはアルミニウムなどはガラスと比較して加工を行いやすく、かつ、破損の心配が少なくなる。

【0041】尚、上記実施の形態2においては、載置台33の全てがレーザ光32を反射する材質にて形成される例を示したがこれに限られることはなく、少なくとも載置台33のうち、載置台33と固定シート部材18とが接し、かつ、半導体ウエハ19の加工領域に対応するレーザ照射部が、レーザ光32を反射する材質にて形成されていれば、上記実施の形態2と同様の効果を奏することは言うまでもなく、例えば載置台33の表面のみが、レーザ光32を反射する材質にて成る場合などが考えられる。

【0042】実施の形態3. 図4はこの発明における実施の形態3のレーザ加工装置の構成および加工工程を示す図である。図において、上記各実施の形態と同様の部分は同一符号を付して説明を省略する。34は固定シート部材18を載置して真空吸着にて固定する載置台で、例えば、レーザ光を透過する材質、または、レーザ光を一反射する材質にて形成されることが考えられる。34aは載置台34の上部に形成された、逆台形の凹部、35は半導体ウエハ19の加工領域の外側に形成されるとともに、逆台形の凹部34aの底部の周縁部に形成された吸着用穴である。

【0043】次に上記のように構成された実施の形態3のレーザ加工装置の加工工程について説明する。まず、上記各実施の形態と同様に、固定シート部材18を載置台34上に載置する(図4(a))。次に、第1のバルブ24を開放して真空ポンプ23を作動させ、真空ゲージ25にて確認しながら、吸着用穴35から所望の負圧をかけ、載置台34に固定シート部材18を真空吸着させる(図4(b))。この際、図4(b)からも明らかなように、固定シート部材18は載置台34の上面の逆台形の凹部34aの形状に変形して吸着されている。

【0044】このように、載置台34の吸着用穴35より内側が、吸着用穴36より外側より低く形成されているため、真空吸着の際に、載置台34の半導体ウエハ19の加工領域の外側に吸着用穴35が形成されていても、載置台34と固定シート部材18との間に気泡が残ることなく真空吸着を行うことができる。

【0045】次に、上記各実施の形態と同様に、レーザ 光にて半導体ウエハ19の加工を行う。この際、吸着用 穴35は半導体ウエハ19の加工領域の外側に形成され ているため、吸着用穴35にレーザ光が照射されること はない。よって、吸着用穴35内にゴミなどが存在して も、加熱されることはない。

【0046】次に、第1のバルブ24を閉じるとともに、真空ポンプ23の動作を停止する(図4(a))。すると、固定シート部材18は載置台34の逆台形の凹部34aから離れ、元の状態にもどる。そして、上記各実施の形態と同様に、固定シート部材18を載置台34から離脱し、固定シート部材18から半導体ウエハ19を取り外す。

【0047】上記のように構成された実施の形態3によれば、上記各実施の形態と同様の効果を奏するのはもちろんのこと、吸着用穴35内のゴミなどによる加熱が防止され、固定シート部材18が加熱されることによる不具合を解消することができる。

【0048】尚、上記各実施の形態において、被加工物として半導体ウエハを用いる例を示したがこれに限られることはなく、レーザ光を吸収する部分を有する被加工物であればよいことは言うまでもなく、特に微細な加工を要求されるものに優れた効果を有するものである。ま

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た、半導体ウエハの半導体デバイス間を切断する例を示したがこれに限られることはなく、例えば穴あけ加工など、レーザ光による溶断を利用する加工であればよいことは言うまでもなく、同様の効果を奏するものである。 又、載置台と固定シート部材との真空吸着による離脱を、吸着用穴に大気圧以上の気圧をかけ、載置台から固定シート部材を浮かせるようにして離脱すれば、被加工物への損傷を防止することができる。

[0049]

【発明の効果】以上のように、この発明の請求項1によれば、レーザ光を吸収する部分を有する被加工物を接着して固定し、かつ、レーザ光を透過する材質にて成る固定シート部材と、固定シート部材を載置して固定する載置台とを備え、被加工物にレーザ光を照射して被加工物を溶断するレーザ加工装置において、載置台は、載置台と固定シート部材とが接し、かつ、被加工物の加工領域に対応するレーザ照射部が、レーザ光を透過する材質にて形成されているので、載置台が加熱されることが防止され、シート部材を載置台から容易に離脱でき、被加工物の損傷を防止することができるレーザ加工装置を提供することが可能となる。

【0050】また、この発明の請求項2によれば、請求項1において、レーザ光としてYAGレーザを用い、載置台のレーザ照射部がガラスにて形成されているので、載置台がレーザ光を透過することが確実にできるので、シート部材を載置台から容易に離脱でき、被加工物の損傷を防止することができるレーザ加工装置を提供することが可能となる。

【0051】また、この発明の請求項3によれば、レーザ光を吸収する部分を有する被加工物を接着して固定し、かつ、レーザ光を透過する材質にてなる固定シート部材と、固定シート部材を載置して固定する載置台とを備え、被加工物にレーザ光を照射して被加工物を溶断するレーザ加工装置において、載置台は、載置台と固定シート部材とが接し、かつ、被加工物の加工領域と対応するレーザ照射部が、レーザ光を反射する材質にて形成されているので、載置台が加熱されることが防止され、シート部材を載置台から容易に離脱でき、被加工物の損傷を防止することができるレーザ加工装置を提供することが可能となる。

【0052】また、この発明の請求項4によれば、請求項3において、レーザ光としてYAGレーザを用い、載置台のレーザ照射部が銅、または、金、または、アルミニウムにて形成されているので、載置台がレーザ光を反射することが確実にできるので、シート部材を載置台から容易に離脱でき、被加工物の損傷を防止することができるレーザ加工装置を提供することが可能となる。

【0053】また、この発明の請求項5によれば、レー 1 固定冶具、22,35 吸着用穴、23 具空ボンザ光を吸収する部分を有する被加工物を接着して固定す プ、24 第1のバルブ、25 真空ゲージ、26 加る固定シート部材と、固定シート部材を載置して真空吸 50 圧手段、27 第2のバルブ、28 半導体デバイス、

着にて固定する載置台とを備え、被加工物にレーザ光を 照射して被加工物を溶断するレーザ加工装置において、 載置台の固定シート部材を真空吸着するための吸着用穴 が、被加工物の加工領域の外側に形成されているので、 吸着用穴からの加熱の発生が防止され、シート部材を載 置台から容易に離脱でき、被加工物の損傷を防止するこ とができるレーザ加工装置を提供することが可能とな る。

【0054】また、この発明の請求項6によれば、請求項5において、載置台の上部は、逆台形の凹状にて形成され、吸着用穴を凹状の底部の周縁部に備え、真空吸着時に、固定シート部材が載置台の凹状に沿って変形して載置台上に真空吸着されるので、固定シート部材と載置台とを確実に真空吸着することができるレーザ加工装置を提供することが可能となる。

【0055】また、この発明の請求項7によれば、レーザ光を吸収する部分を有する被加工物を接着して固定する固定シート部材と、固定シート部材を載置して真空吸着にて固定する載置台とを備え、被加工物にレーザ光を照射して被加工物を溶断するレーザ加工装置において、載置台の固定シート部材を真空吸着するための吸着用穴と、載置台からの固定シート部材の離脱時に、吸着用穴に大気圧以上の気圧をかける加圧手段を備えたので、固定シート部材を容易に載置台上から離脱することができるレーザ加工装置を提供することが可能となる。

【図面の簡単な説明】

【図1】 この発明の実施の形態1によるレーザ加工装置の構成を示す図である。

【図2】 図1に示したレーザ加工装置の加工方法を示す図である。

【図3】 この発明の実施の形態2によるレーザ加工装置の加工方法を示す図である。

【図4】 この発明の実施の形態3によるレーザ加工装置の構成を示す図である。

【図5】 従来のレーザ加工装置の加工方法を示す図である。

【図6】 図5にて使用される従来のレーザ加工装置の構成を示す図である。

【図7】 他の従来のレーザ加工装置の加工方法を示す 40 図である。

【図8】 図7にて使用される従来のレーザ加工装置の構成を示す図である。

【図9】 他の従来のレーザ加工装置の問題点を説明するための図である。

【符号の説明】

16 本体、17,33,34 載置台、18 固定シート部材、19 半導体ウエハ、20 固定リング、2 1 固定冶具、22,35 吸着用穴、23 真空ポンプ、24 第1のバルブ、25 真空ゲージ、26 加田手段 27 第2のバルブ、28 半導体デバイス、

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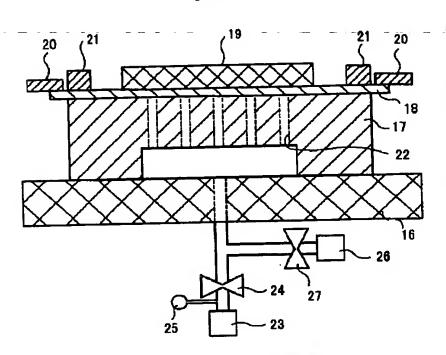
11

29 金属部、30 レーザ光、31 溶解凝固部、3 2 レーザ光、32a 反射光、34a 逆台形の凹

部。

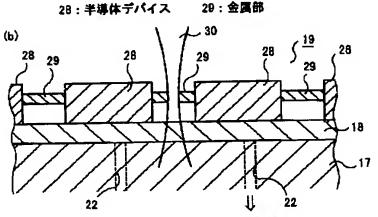
【図1】

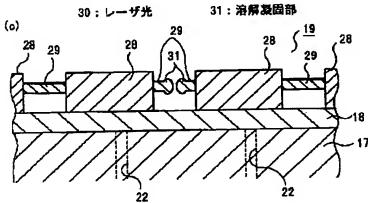
【図2】



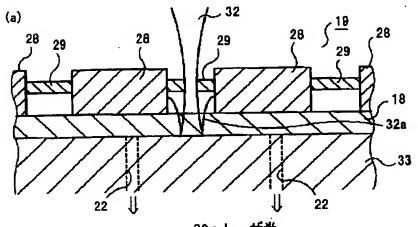
16:本体22:吸着用穴17:載置台23:真空ポンプ18:固定シート部材24:第1のパルブ19:半導体ウエハ25:真空ゲージ20:固定リング26:加圧手段21:固定治具27:第2のパルブ

(a) 28 29 28 29 28 29 28 29 28 29 18 28: 半導体デバイス 29: 金属節

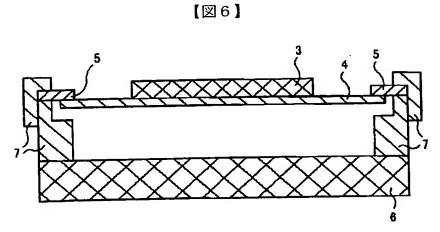


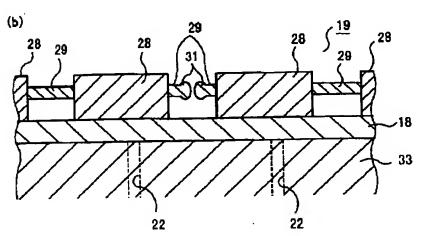


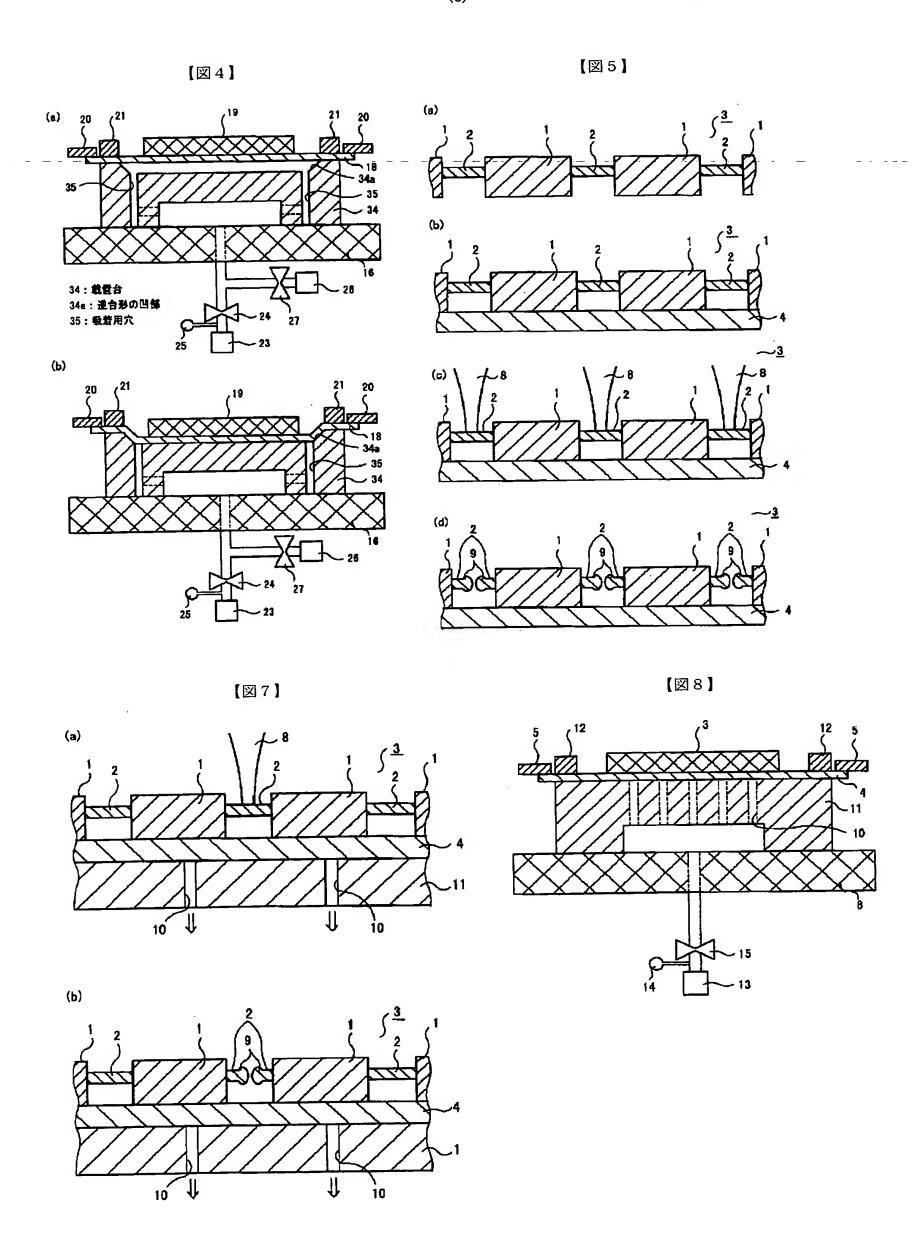
【図3】

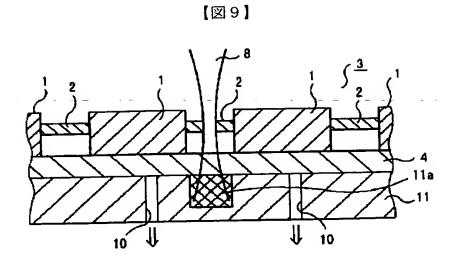


32:レーザ光 32a:反射光 33:載置台









フロントページの続き

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